Connecting Berry's phase and the pum ped charge in a Cooper pair pum p

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The properties of the tunnelling-charging H am iltonian of a C ooper pair pump are well understood in the regime of weak and interm ediate Josephson coupling, i.e. when E_J . E_C . It is also known that B enry's phase is related to the pumped charge induced by the adiabatical variation of the eigenstates. We show explicitly that pumped charge in C ooper pair pump can be understood as a partial derivative of B enry's phase with respect to the phase di erence across the array. The phase uctuations always present in real experim ents can also be taken into account, although only approximately. Thus them easurement of the pumped current gives reliable, yet indirect, information on B enry's phase. As closing remarks, we give the di erential relation between B enry's phase and the pumped charge, and state that the mathematical results are valid for any observable expressible as a partial derivative of the H am iltonian.

Josephson junction devices, e.g. Cooper pair box, superconducting single electron transistor (SSET) and Cooper pair pump (CPP), have been extheoretically^{1,2,3,4,5,6} tensively studied both and experim entally.^{7,8,9,10,11,12} (For a recent review, see Ref. 13.) Possible applications include coherent Cooper pair pumping² with related decoherence studies^{6,9} or m etrological applications, 1^{14} and the use of these devices as superconducting quantum bits (squbits) in quantum com putation.^{1,8,15} In this paper we focus on CPP whose idealised tunnelling-charging Hamiltonian has been studied in detail in Refs. 2,16,17. For closed loops in the param eter space, we relate the pum ped charge to Berry's phase, a well-known geometrical phase attained by an adiabatically evolving eigenstate of a time-dependent Ham iltonian.^{18,19,20} Some applications of geometrical phases in m esoscopic system s, are discussed in R efs. 5,21 and the references therein. We illustrate the results both for the SSET and a CPP, and consider the e ects due to phase uctuations, present when experim entally m easuring the pum ped current.

In a CPP the pumping of Cooper pairs is induced by cyclic variation of the gate voltages while the evolution of the total phase di erence across the array, , is either xed by ideal biasing or stochastically decoherent. Theoretical predictions are based on the adiabatic evolution of the eigenstates which splits the induced current into two parts:^{2,16} The direct supercurrent, which ows constantly and is proportional to the -derivative of the dynam ical phase of the eigenstate. The other part, the pumped charge, is explicitly induced by the action of pum ping and proportional to the -derivative of Berry's phase for closed loops. Existence of such a relation was already implicitly stated in Ref. 2. The underlying reason for these connections is that the supercurrent operator I_S is an operator derivative²² of the full H am iltonian with respect to . This also implies that all of the results obtained in this paper are valid for any observable expressible as a partial derivative of the corresponding Ham iltonian. However, in real applications it m ight be reasonable to use the nonadiabatically attained geom etrical phase instead of Berry's phase.¹⁵

A schematic view of a CPP is shown in Fig.1. We assume that the gate voltages $V_{g;j}$ are independent and externally operated. The ideally operated bias voltage across the array, V, controls the total phase di erence, , according to d =dt = 2eV=~. In the absence of bias voltage, remains xed and becomes a good quantum num ber.^{2,23} C onversely, the conjugate variable M, the average num ber of tunnelled C ooper pairs, becomes com – pletely undetermined.

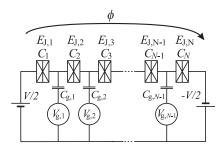


FIG.1: An ideal superconducting array of Josephson junctions (CPP). Here C_k and $E_{\rm J,k}$ are the capacitance and the Josephson energy of the $k^{\rm th}$ junction, respectively. The total phase di erence across the array, , is a constant of motion in the absence of the external bias voltage V .

The tunnelling-charging Ham iltonian

$$H = H_{C} (q) + H_{J}; \qquad (1)$$

is assumed to be the correct description of the microscopic system, neglecting quasiparticle tunnelling as well as other degrees of freedom. The charging Hamiltonian H_C (q) depends on the normalised gate charges, $q := (q_1; :::; q_{N-1})$, and the number of Cooper pairs on each island, $n = (n_1; :::; n_{N-1})$, according to $\ln H_C$ (q) $j_1^{n_1} = E_C$ (n q) $n_{;n^{n_1}}$. The function E_C (x) gives the details of the charging energy, see e.g. R ef. 16. The Josephson (tunnelling) Hamiltonian is given by

$$H_{J} = \sum_{k=1}^{N} E_{J;k} \cos(k); \qquad (2)$$

where $E_{J;k}$ is the Josephson coupling energy of the k^{th} junction. The average supercurrent operator can be w ritten in the form

$$I_{S} = \frac{2e^{X^{H}}}{N \sim} E_{J;k} \sin(k) = \frac{2e^{Q}H}{2e^{Q}}; \quad (3)$$

where the operator derivative²² is de ned as

$$\frac{@H}{@} \coloneqq \lim_{0 \le i \le 0} \frac{H(0) H(1)}{0} = H(1)$$
(4)

In the preferred representation, the parameter space is an N-dimensional manifold \mathbb{R}^{N-1} S¹, where the elements are of the form $\mathbf{p} = (\mathbf{q};)$ with 2 [D;2N). For N = 2, the system reduces to a SSET whose H am iltonian is discussed in Ref. 24. A symptotically exact eigenvectors for strong Josephson coupling are given in Ref. 25.

W e will study the adiabatic evolution of instantaneous energy eigenstates in i, while changing the gate voltages along a closed path :t 7 p(t) = (q(t); (t)) with t 2 [0;]. This induces a charge transfer $Q_{tot} \Rightarrow Q_s +$ Q_p , where the pumped charge, Q_p , depends only on the chosen path, , determ ined by the gating sequence, while the charge transferred by the direct supercurrent, Q_s , also depends on the rate of operation of the gate voltages, i.e., the value of . The total transferred charge, in units of 2e, for state jn i becom es^{r17}

$$Q_{tot} = \frac{\underline{\theta}_{m}}{\underline{\theta}} + 2 \operatorname{Re} \operatorname{Im} \frac{1}{2} \operatorname{Miz}$$
(5)

Here $\hat{M} = i\theta = 0$ is the operator for average number of tunnelled C coper pairs, $m = \int_{0}^{\infty} (E_m(t)=\sim)dt$ is the dynam ical phase and jum i is the change in the eigenstate jn i due to a di erential change dp = (dq; d). A change d in the phase di erence at p induces no pum ped charge as we nd $dQ_p = 2 \text{Im} [\hbar \hat{M} \text{ m }] \hat{M} \text{ m }] d = 0$. In other words, the bias voltage V induces no pum ped charge for xed gate voltages.

The expression for Q_p is rather similar to the corresponding Berry's phase^{18,19}

It should be stressed that Eqs. (5) and (6) are well dened also for open paths. The derivative d in Eq. (6) is an exterior derivative so, for a closed path , we may integrate Berry's curvature over a two-surface²⁰

$$m() = i \qquad \frac{2^{N} \times N}{k + 1} \sum_{k=1}^{N} \frac{2^{N}}{k} \qquad \frac{2^{N} \times N}{k} \qquad \frac{2^{N} \times N}{k + 1} \sum_{k=1}^{N} \frac{2^{N} \times N}{k} \qquad \frac{2^{N} \times N}{k + 1} \qquad \frac{2^{N$$

where the boundary of S is the path $\frac{26}{\cdot}$

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We now construct an extended path for which Berry's phase is proportional to the charge pumped along the path . Let us de ne a class of closed paths f, g by , :t 7 p(t) = (q(t); (t) + '), where t 2 [0;], so

that $_0 = .$ The inverse of a path is the same path traversed in the opposite direction, which also holds for paths with distinct end points. We de ne an additional class of paths f'_pg according to '_p :t 7 (q; + t'), where t2 [0;1]. The extended path

$$P_{\text{ext}} \coloneqq 0 \quad P_{\text{p}}(0) \quad P_{\text{p}}(0)$$

is also closed and spans a two-dimensional integration surface whose width in -direction is '. By traversing the boundary the contributions from ' $_{p(0)}$ and ' $_{p(0)}^{1}$ naturally cancel, and we nd

$$\binom{7}{ext} = \binom{7}{1} = \binom{7}{1} (7) = \binom{7}{1$$

Next we take the lim it '! 0 and consider a strip of in nitesimalwidth d between $_{\rm d}$ and $_{\rm 0}$ as illustrated in Fig. 2. This means that in Eq. (7) we have either

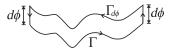


FIG.2: A closed path has been attened, i.e. the ends of meet. The in nitesimal pieces of length d are identical, but traversed in opposite directions. The two-dimensional integration surface S $_{\rm rd}$ is spanned between orbits and $_{\rm d}$. Berry's phase corresponding to the boundary of S $_{\rm rd}$ is identical to $Q_{\rm p}$ () d, with $Q_{\rm p}$ () de ned in Eq. (10).

 $dq_k = d$ or $dq_l = d$ as the full length of integration and we can factor d from the expression for Berry's phase. By rephrasing Q_p in Eq. (5) as

$$Q_{p}() = \frac{X^{1}}{1} \quad \frac{2 \operatorname{lm} j 2 \operatorname{jn} i}{2 \operatorname{eq}_{k}} \quad \frac{2 \operatorname{lm} j 2 \operatorname{lm} i}{2 \operatorname{eq}_{k}} \quad \frac{2 \operatorname{lm} i}{2 \operatorname{lm} i} 1 \operatorname{eq}_{k}} \quad \frac{2 \operatorname{lm} i}{2 \operatorname{lm} i} 1 \operatorname{eq}_{k} \quad \frac{2 \operatorname{lm} i}{2 \operatorname{lm} i} 1 \operatorname{lm} i} 1 \operatorname{lm} i 1$$

we see that it is identical to Berry's phase in Eq. (7) apart from the factor d. By taking the lim it from the equivalent result $\lim_{r \to 0} (() (r)) = r$, we obtain the rst m ain result

$$Q_{s} + Q_{p} = 0_{m} = 0_{m$$

This clearly shows the connection between Berry's phase and the pumped charge, which is completely analogous with the connection between the dynam ical phase and the accumulated charge due to direct supercurrent.

W e now proceed in the opposite direction and consider strips of nite width instead of in nitesimal ones. By integrating the pumped charge with respect to over the set $f \cdot g$, we obtain the average pumped charge per cycle, $Q_{p;ave}$, as

$$Q_{p,ave} = \frac{1}{2} \int_{0}^{Z} Q_{p}() d = \frac{(0)}{2} \int_{0}^{Z} (12)$$

The graphical representation of this situation in a threejunction CPP and a SSET, are shown in Fig. 3 (I,II) and

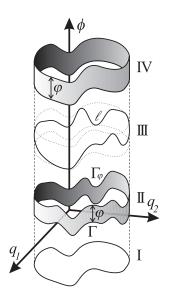


FIG. 3: I) A projection of path in the $(q_1;q_2)$ -plane. II) A strip of nite width ' based on the path . III) The uctuations of on a single pumping cycle, '. IV) Ideal operation of gate voltages produces a strip bounded by the planes = $_0$ and = $_0 + '$. The same result is obtained approximately after many cycles with restricted, stochastic uctuations of .

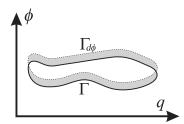


FIG. 4: Pumping of Cooper pairs in SSET recuires also an ideal control of . The projection of the path onto q-space is a line traversed back and forth.

in Fig. 4, respectively. The cases are qualitatively di erent, because there is only one q-coordinate in a SSET.

We now wish to relate the above results to actual measurements of C ooper pair pumping. First, consider a closed path corresponding to a xed value of $_0$ as in R ef. 2. Under ideal operation of gate and bias voltages we can change slightly between each cycle and obtain a clean strip bounded by the planes = $_0$ and = $_0 + '$ as shown in Fig. 3 (IV). Combined with Eq. (12) this amounts to an important result for an ideal CPP: The measured pumped charge per cycle (i.e. Q_{prave}) yields direct inform ation about di erences of Berry's phases.

O btaining the same information in a real experiment is not so straightforward. Neither the phase dierence, , nor the gate voltages are ideally controlled. Nevertheless, we try to partially circum vent these problems using reasonable approximations. First, we assume that the gate voltages are operated accurately enough, so that the projections onto q-space nearly coincide. Additionally, uctuates stochastically, but these uctuations are restricted during time intervals shorter than the decoherence time, $\stackrel{6}{.}$ For times larger than the uctuations mount up too large and the phase coherence of the system is lost.

The decoherence is induced by any interaction between the quantum mechanical system and the environment. In a well prepared experiment, e.g. a CPP can be isolated from its surroundings so that the main contribution to is given by the electrom agnetic environment in the vicinity of the sample and the elects due to nite temperature, restricting the measurements to subkelvin regime.

The decoherence time can be calculated theoretically from the uctuation-dissipation {theorem as in Ref. 6 or by looking at coherences, i.e., o -diagonalelem ents of the density matrix. The Ham iltonian in the presence of the electrom agnetic environm ent reads

$$H = H_{C} (q) + H_{J} + H_{env} + H_{int};$$
 (13)

where $H_{env} = {P \atop j} (b_j^v b_j + 1=2) \sim !j$ and b_j^v and b_j are the creation and annihilation operators of the bosonic environm entalm ode j with energy $\sim !j$, respectively.²⁷ A s an example, we consider a SSET but it should be stressed that the result generalises for any number of junctions. We write the density matrix ${}^{R} = {}^{R} {}^{Ry}$ in the basis consisting of two SSET charge states, fjm $ig_{m=0}^1$ and environm entalm odes fj $k = (k_1; k_2; :::)$ ig. Then the H am iltonian describing the interaction between SSET and the environm ent becomes^{27,28}

$$H_{int} = \frac{p_{-X}}{i} \sim \frac{1}{j} \frac{\overline{Z_{j}}}{R_{K}} b_{j} \quad b_{j} \quad \frac{1}{0} \quad i \quad (14)$$

where Z_j is the impedance of the mode j and $R_K = h=e^2$ / 25.8 k is the resistance quantum .

The equation of motion for ${}_{I}^{k}$ in the interaction picture is given by the Liouville equation, i~ (d ${}_{I}^{k}$ (t)=dt) = $[H_{int;I}; {}_{I}^{k}$ (t)]. By solving the di erential equation for the coherence matrix elements and tracing out the environmental con gurations k we obtain the nalresult

$$_{I;12}$$
 (t) = $_{I;12}$ (0) exp [2R eJ (t)]; (15)

which corresponds to the same time scale as given by the uctuation-dissipation -6-theorem ⁶. Here J(t) is the phase-phase correlation function J(t) = h['(t) '(0)]'(0)i and $_{\rm I} = h_{\rm I}^{\rm K} i_{\rm R}$.²³ In case of purely resistive electrom agnetic environment, R_e, Eq. (15) yields⁶ ' [~=(16k_BT)]R_K=R_e, where we have assumed nonzero temperature and k_BTt=~ 1. For realistic measurement parameters, e.g. T = 10 mK and R_e = 10 , one obtains a rather long time ' 0:4 s.

Returning to Berry's phase, we assume an initial value $_0$ and consider time intervals shorter than , e ectively restricting to a nite range $[_1; _2]_3 _0$. If su ciently m any (identical) cycles of gate voltages are performed during this time, the uctuations of yield a relatively thick m esh of trajectories within the strip. A though

the 'w eights' for di erent values of are uneven, we approximate the mesh with a uniform distribution which is a subset of the range [1; 2]. This corresponds to a well-de ned strip as in the ideal case of Eq. (12) and is presented in Fig. 3 (IV). A cycle, ', with exaggerated

uctuations in , is shown in Fig. 3 (III). Due to the stochastic nature of the uctuations, it is in possible to predict the correct range to be used. Nevertheless, for periods that are short enough, the correspondence between Berry's phase and the measured pumped charge exists in the sense of Eq. (12). If the end points of the fullpum ping cycle are su ciently close, Eq. (11) is valid, at least in the fram ework of the model.

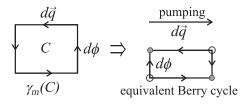


FIG. 5: An in nitesimal cycle C corresponding to Berry's phase $_{\rm m}$ (C) consists of four legs. The charge transfer Q $_{\rm p}$ for a xed is identical to Berry's phase induced by traversing the legs in the directions shown on the right-hand-side divided by d . This path can not be continuously followed in the param eter space.

As a nalnote, we construct the di erential relation between Berry's phase and the pumped charge. Let us

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consider Berry's phase m induced by an in nitesimal closed cycle C at (q;) with sides dq and d as shown by the left-hand-side of Fig. 5. On the right-hand-side, the pum ped charge due to dqmultiplied by d , is identical to Berry'sphase induced by the discontinuous path below it. By following any closed pumping path and integrating the pum ped charge, we recover Eq. (11). If the path is not a closed one, a nontrivial integration with respect to

remains, regardless of the width of the strip.

In conclusion, we have shown explicitly how the pum ped charge in Cooper pair pum p can be understood as a partial derivative of Berry's phase with respect to the phase di erence across the array. We have only used the fact that the supercurrent operator I_{S} is an operator derivative of the full H am iltonian. Thus these results generalise for any observable with this property. We have also shown how one could obtain information about Berry's phase by measuring the pumped current in a CPP.

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